NSN 5962-01-248-8649

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-248-8649

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Features Provided:

Hermetically sealed and burn in and electrostatic sensitive and programmed

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds access

Memory Device Type:

Prom

Memory Capacity:

1024k x 8

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

24 printed circuit

Specification Data:

81349-mil-m-81349/209 government specification

Shelf Life:

N/a

Unit Of Measure:

```
---
```

Demilitarization:

No

Fiig:

A458a0